



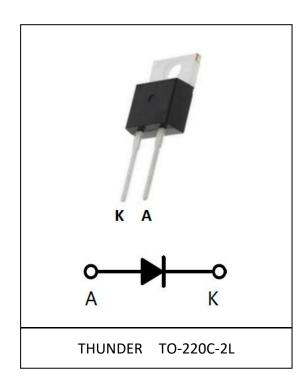
#### **Thunder High Power Products**

# FRED Ultrafast Soft Recovery Diode, 30A

#### **Features:**

- Ultrafast Recovery
- 175°C operating junction temperature
- High frequency operation
- Low power loss, less RFI and EMI
- Low I<sub>R</sub> value
- High surge capacity
- Epitaxial chip construction

Product Summary		
VR	300 V	
lf(AV)	30A	
trr	26 ns	



## **Description/Applications**

These diodes are optimized to less losses and EMI/RFI in high frequency power conditioning system. The soft recovery behavior of the diodes offers the need as snubber in most applications. These devices are ideally suited for HF welding power converters and other applications where the switching losses are not significant portion of the total losses.

### **Absolute Maximum Ratings**

Parameter	Symbol	Test Conditions	Values	Units
Repetitive peak reverse voltage	Vrrm		300	V
Continuous forward current	lf(AV)	Tc =110°C	30	
Single pulse forward current	IFSM	Tc =25°C	300	А
Maximum repetitive forward current	IFRM	Square wave, 20kHZ	150	
Operating junction	Тј		175	°C
Storage temperatures	Tstg		-55 to +175	°C

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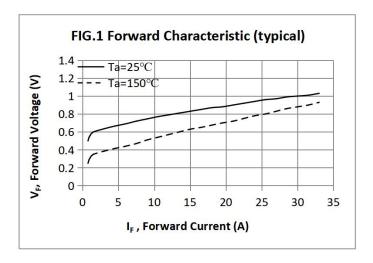
## Electrical characteristics (Ta=25°C unless otherwise specified)

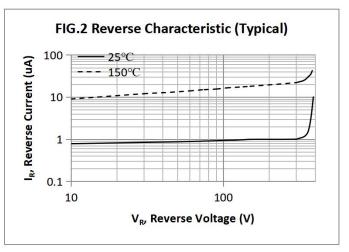
Parameter	Symbol	Test Conditions	Min	Тур.	Max.	Units
Breakdown voltage	VBR,	Ir=100⊬A	300			
Blocking voltage	$V_R$	IK-100MA	300			
Forward voltage (Per Diode)	VF	IF=30 A		0.96	1.20	V
		IF=30 A, Tj =125°C		0.85	1.00	
Reverse leakage current(Per Diode)	lr -	Vr= Vrrm			10	
		Tj=150°C, Vr=300V			100	μ <b>Α</b>
Reverse recovery time(Per Diode)		I <sub>F</sub> =0.5A, I <sub>R</sub> =1A, I <sub>RR</sub> =0.25A		35	45	nc
	trr	I <sub>F</sub> =1A,V <sub>R</sub> =30V, di/ <i>dt</i> =200A/us		26	40	ns

#### **Thermal characteristics**

Paramter	Symbol	Тур	Units
Junction-to-Case	Rejc	1.2	°C/W

# **Electrical performance (typical)**



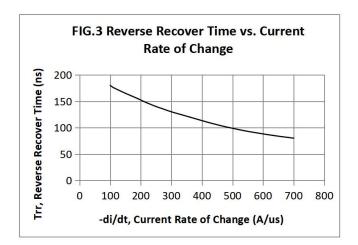


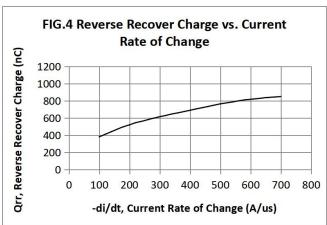
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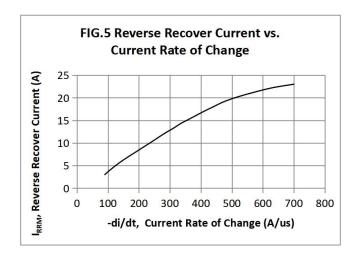


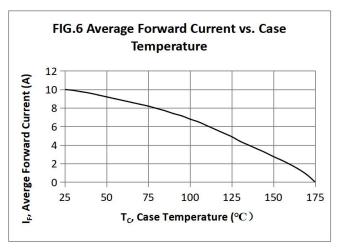


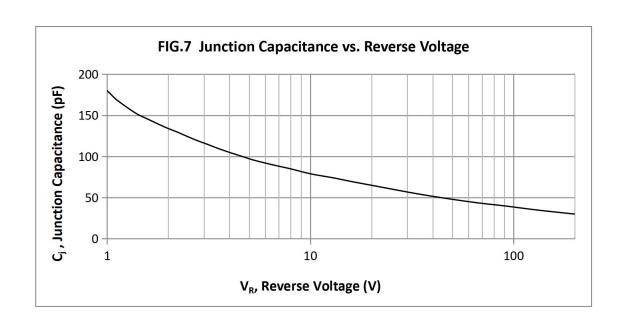












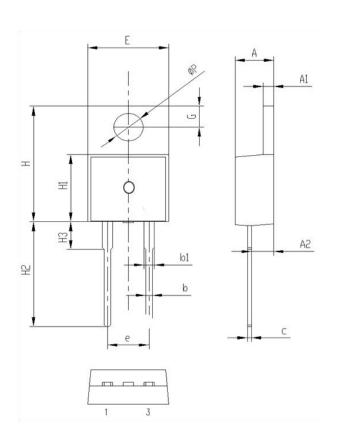
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## **Package Information**

#### **TO-220C-2L PACKAGE**



S. was la a l	单位 mm			
Symbol	Min	Nom	Max	
А	4.30	4.50	4.70	
A1	1.2	1.3	1.4	
A2	2.30	2.40	2.50	
b	0.60	0.8	1.00	
b1	1.1	1.3	1.5	
С	0.40	0.50	0.60	
е	4.88	5.08	5.28	
E	9.8	10.0	10.2	
Н	15.5	15.7	15.9	
H1	9.00	9.20	9.40	
H2	12.5	13.0	13.5	
Н3	2.80	3.0	3.20	
G	2.60	2.8	3.00	
ФР	3.40	3.6	3.80	

#### **Notice**

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#### -Headquarters

WuXi Thunder Microelectronics Incorporated Limited

Building E1-9F, No.200 LingHu Road, XinWu district, WuXi, China 214135

Tel:+86-510-85160109 Fax:+86-510-85160109

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